

# Numerical Thermal Stress Analysis on Semiconductors with Nano-Fluid Coolant

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## Abstract

During the course of normal operation, electrical components made from semiconducting materials undergo significant stress from heating. This causes parts to wear out more quickly or, in the more extreme cases, fail altogether. In order to maintain a stable operating temperature, many different types of cooling systems have been used. Our work investigates the best materials to use in these systems, carefully considering effectiveness, cost, and longevity in our assessment. Ansys simulation software was used to simulate the effects of different coolants on removing heat from a semiconductor. The coolants are air, water, and aluminum oxide. Though we didn't model the results of forced convection across these materials, the natural convection heat transfer results in finding the more efficient coolant. Considering liquid cooling methods for semiconductor-based devices, the kind of fluid plays a vital role in the transfer of energy. The Aluminum Oxide was selected in a 2

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*Index terms*— thermal stress, nano-fluid aluminum oxide coolant, semiconductors.

## 1 I. Introduction

Because many of these components can only work properly within a relatively narrow temperature range, an entire industry has materialized that is dedicated to keeping them cool [1]. Consequently, a great deal of time and money has been spent researching the best materials for transferring energy from the delicate components and releasing it into another medium [2]. We entered this project with the goal of finding the most suitable materials for cooling semiconductor-based electrical components like CPUs. The two types of cooling methods examined are the use of heat sinks and pumped liquid cooling.

First, we examine cooling systems using heat sinks. Heat sinks transfer heat from the component via conduction and release that heat in the surrounding air through both convection and radiation. The primary factor in determining the effectiveness of a material for this process is its thermal conductivity, though thermal diffusivity is also a major factor [3]. The former determines the material's ability to transfer heat away from the source while the latter speaks to its ability to move the energy throughout itself, as well as radiate it away. Usually, heat sinks are used in a forced convection system with air being moved across the heat sink fin [4]. We examined several materials for this section and have arranged them within Table 1. Aluminum, reminiscent of aluminum and a thermal conductivity comparable to the much heavier copper, CarbAl provides the best attributes of both materials. Its thermal diffusivity is also significantly higher than the others, allowing for better energy flux throughout itself. This material was designed in 2008 by Applied Nanotech Inc. and remains a superior material for many applications, including heat sinks for high end applications.

## 2 II. Nanofluid Simulation

With regards to liquid cooling systems for semiconductor-based devices, the type of fluid plays a significant role in the transfer of energy. We selected Aluminum Oxide in a 2% solution and 40nm wide particles to simulate for our nanofluid as it is commonly used in the industry and data for it was readily available [7] [8]. The

43 properties of the Materials used (simulated) in this study are provided in tables 2, 3 and 4. Borondoped silicon  
44 and phosphorus-doped silicon, Air, Water, Aluminum oxide nanoparticles for nanofluid.

### 45 3 Analysis Setup & Methodology

46 Simulation was done using convection to transfer heat from SM to cooling fluid. Convective heat transfer  
47 coefficient ( $h_c$ ) was used the principal property of fluid for simulation.

48 We found that this coefficient depended type of medium such as gas or liquid, flow properties such as velocity,  
49 viscosity and other flow and temperature dependent properties [8].

50 Many of the research papers we found used other values and coefficients that are the norm in the field of  
51 thermodynamics. Nusselt, Rayleigh, and Reynolds numbers were discussed in these papers, however, since these  
52 are out of the scope of this class, we decided to use convection [12][13][14]. The terms stated above do depend  
53 on convection so it's not as to completely ignore the experimental results from researchers; convection allowed  
54 us to simplify our model.

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### 56 5 ANSYS

57 Main purpose was to compare the cooling capabilities of air, water, and nanofluids by forced convection. Finding  
58 comparable values for the heat transfer coefficients (HTC) of each of these values was a problem, mainly because  
59 it was difficult to find experimental results that had been performed under the same conditions [12][13][14][15].  
60 However, we were able to find papers that contained the information for water and aluminum oxide nanofluids  
61 although there were calculations needed as well as estimating values from graphs demonstrating results. These  
62 papers contained the needed coefficients for water and Al-Ox under similar conditions such as mass flow (1.5  
63 liters per minute) and temperature (40?) therefore we could use comparable values for their respective HTC's  
64 [7,8].

65 A simplified geometry was used in the simulation. The actual geometry of a transistor (our example for  
66 semiconductor) was convoluted. In addition, the electronic components had to be omitted from the modeling  
67 because the focus was on thermal impact and because it was simpler to declare one region of the geometry as  
68 the heat source. Another simplification had to do with energy bands, to understand and model such concept, an  
69 understanding of Fermi function, Fermi-Dirac distribution, Boltzmann approximation, and electron concentration  
70 under different temperature conditions [12][13][14][15].

71 What we expected to see in the ANSYS Fluent heat maps was the heat dissipated from the source out through  
72 the boundaries making contact with the fluid. However, this was not the case the first few times that we ran the  
73 simulation. This was due to the geometry of our model; we had placed one geometry meant to represent the fluid  
74 above the geometry representing the semiconductor. There was an issue with the boundary where the surfaces  
75 met and thus, we decided to change our approach by convection.

76 Once we read up on how convection worked, we could set up our model an analogous fashion [5]. This resulted  
77 in a simpler model where only a single geometry was needed which was meant to represent the semiconductor.

78 Using ANSYS Fluent, the mesh was imported and given three different boundaries. The bottom edge along  
79 with both vertical edges were all labeled "outlet boundary" meaning these edges were to make contact with  
80 our test fluids (air, water, nanofluid). The top edge was the heat source; it was meant to be analogous to the  
81 conduction band on a transistor although in reality the situation is complex [15]. The surface of the body was  
82 the third boundary and this is where the properties of a semiconductor were applied to. A nanofluid composed  
83 of 98% water and 2% aluminum oxide (of particle size 40nm) showed significant improvement (Figure ??) in the  
84 rate of heat transfer over water (Figure ??) and air (Figure 1). Faiza Nazir's results showed a 200% improvement  
85 over water's rate of heat transfer [7].

### 86 6 IV. Results

### 87 7 V. Discussion

88 According to a handful of the research papers and experimental reports, the principal variables that accounted for  
89 the nanofluid's superior performance included: intensification of turbulence or eddy, suppression or interruption  
90 of the boundary layer as well as dispersion or back mixing of the suspended Global Journal of Researches in  
91 Engineering (A ) Volume Xx XII Issue II V ersion I nanoparticles, in addition to the nanoparticles' thermal  
92 conductivity and heat capacity [12].

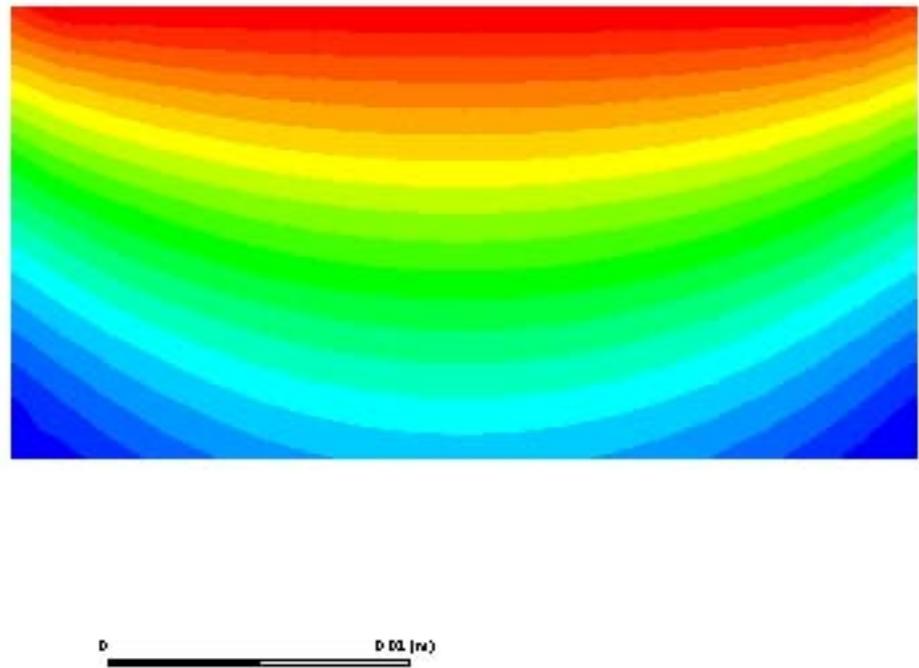
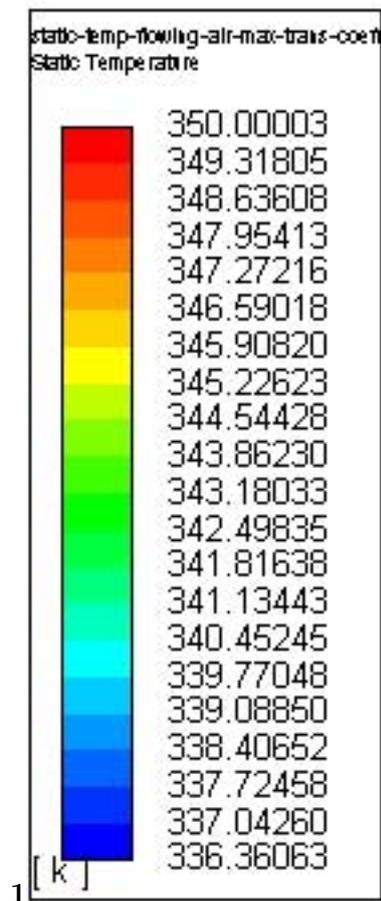
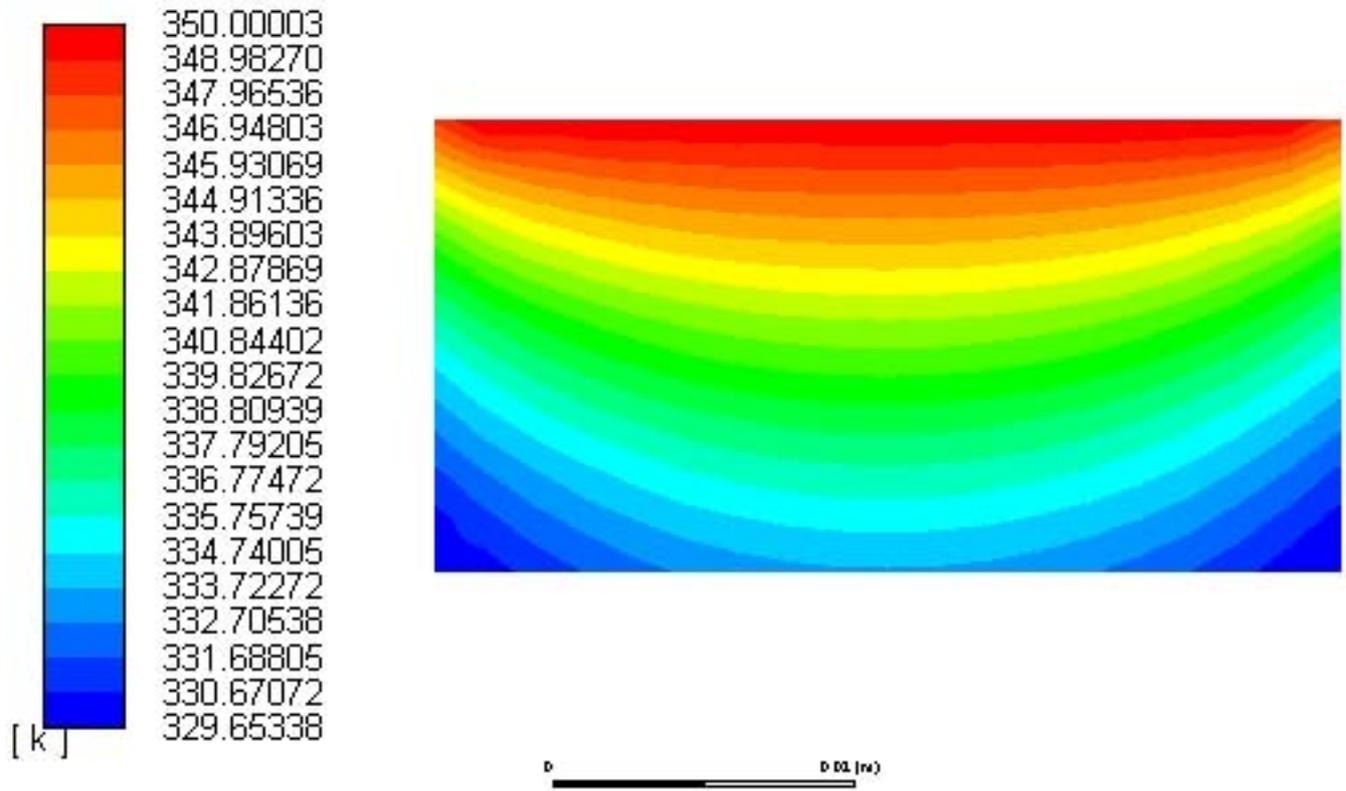


Figure 1: Figure 1 :

static-temp-flowing-0-0-0-0-celsius-1.5pm  
 Static Temperature



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Figure 2: Figure 2 :Figure 3 :

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Figure 3: Table 1 :

2

Figure 4: Table 2 :

3

Figure 5: Table 3 :

Figure 6: Table 4 :

93 **8 VI. Conclusion**

94 The Al<sub>3</sub>O<sub>2</sub> (40nm @ 2% volume) nanofluid had the best cooling performance of the three tested materials.  
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<sup>2</sup>© 2022 Global Journals Numerical Thermal Stress Analysis on Semiconductors with Nano-Fluid Coolant



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